Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
Ll	1127	(702/57,64).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2006/06/06 13:52
L2	1017	(702/65,67,68,107).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2006/06/06 13:53
L3	1225	(702/182).CCLS.	US-PGPUB; USPAT	OR	OFF	2006/06/06 13:54
L4	1015	(702/183).CCLS.	US-PGPUB; USPAT	OR	OFF	2006/06/06 13:57
L5	921	(702/188).CCLS.	US-PGPUB; USPAT	OR	OFF	2006/06/06 14:00
L6	1564	(700/121).CCLS.	US-PGPUB; USPAT	OR	OFF	2006/06/06 14:02
L7	881	(438/5,8,9).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2006/06/06 14:06
L8	6508	(438/14,16,17).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2006/06/06 14:07
L9	62	L8 and (plasma electron) adj density	US-PGPUB; USPAT	OR	ON	2006/06/06 14:07
L10	136	L8 and plasma adj processing	US-PGPUB; USPAT	OR	ON	2006/06/06 14:09
LII	1	plasma adj processing and Gunn adj diode adj ((voltage adj controlled adj oscillator) vco) and @pd>"20060201"	US-PGPUB; USPAT	OR	ON	2006/06/06 14:30
L12	1	Gunn adj diode adj ((voltage adj controlled adj oscillator) vco) and @pd>"20060201"	US-PGPUB; USPAT	OR	ON	2006/06/06 14:31
L13	0	plasma adj processing and Gunn adj diode adj ((voltage adj controlled adj oscillator) vco) and @pd>"20060201"	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:31
L14	0	Gunn adj diode adj ((voltage adj controlled adj oscillator) vco) and @pd>"20060201"	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:31
L15	1	plasma adj processing and Gunn adj diode with ((voltage adj controlled adj oscillator) vco) and @pd>"20060201"	US-PGPUB; USPAT	OR	ON	2006/06/06 14:32
L16	1	plasma adj processing and Gunn adj diode with ((voltage adj controlled with oscillator) vco) and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:32
L17	3	Gunn adj diode with ((voltage adj controlled with oscillator) vco) and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:32
L18	3	((plasma adj processing) (electron adj density)) and semiconductor and diagnostic and resonator and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:33

L19	11	((plasma adj processing) (electron adj density)) and semiconductor and	US-PGPUB;	OR	ON	2006/06/06 14:33
	11	resonator and oscillator and @pd>"20060201"	USPAT; EPO; JPO; DERWENT ; IBM_TDB	O.K		2000/00/00 14.55
L20	1	((plasma electron) adj density and control).ti. and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:36
L21	5	((plasma electron) adj density and (measure measuring measurement)).ti. and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:37
L22	16	((plasma adj processing) ((plasma electron) adj density)) and diagnostic adj system and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:38
L23	2	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) with diode adj voltage and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:39
L24	2	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) with Gunn adj diode and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:40
L25	3	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) with (voltage current) adj monitor and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:40
L26	5	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) with detector with voltage and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:40
L27	3	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) with varactor and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:41
L28	2	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) with voltage near sweep and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:42
L29	2	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) with resonance adj lock-on and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:42
L30	1	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) and (adjust adjusting adjusted change changing changed) with varactor near voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:42
L31	1	((plasma adj processing) ((plasma electron) adj density)) and (control controller controlling controlled) and (modify modifying modified) with varactor near voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:42

L32	2	((plasma adj processing) ((plasma electron) adj density)) and multi-modal adj resonator and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:43
L33	2	multi-modal adj resonator and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:43
L34	2	((plasma adj processing) ((plasma electron) adj density)) and sweep adj generator and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:43
L35	10	((plasma adj processing) ((plasma electron) adj density)) and default adj settings and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:44
L36	13	((plasma adj processing) ((plasma electron) adj density)) and default adj parameters and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:45
L37	1	((plasma adj processing) ((plasma electron) adj density)) and display with diode adj (voltage current)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:48
L38	1	((plasma adj processing) ((plasma electron) adj density)) and display with (varactor detector) adj voltage and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:48
L39	1	((plasma adj processing) ((plasma electron) adj density)) and display with (voltage current) with (vco varactor detector) and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:48
L40	1	((plasma adj processing) ((plasma electron) adj density)) and mode with (select selecting selected selection) with control with data adj acquisition	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:48
L41	1	((plasma adj processing) ((plasma electron) adj density)) and mode with (select selecting selected selection) with control with acquisition	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:49
L42	0	((plasma adj processing) ((plasma electron) adj density)) and mode with (select selecting selected selection) with calibration with acquisition	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:49
L43	2	((plasma adj processing) ((plasma electron) adj density)) and mode with (select selecting selected selection) with control and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:49
L44	2	varactor adj voltage with (electron plasma) adj density and @pd>"20060201"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/06 14:50

L45	0	voltage with ((voltage adj controlled adj oscillator) vco) with (electron plasma) adj density and @pd>"20060201"	USPAT; EPO; JPO; DERWENT	OR	ON	2006/06/06 14:50
			; IBM_TDB			

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